Dual Supply Octal Translating Transceiver

with 3-State Outputs

The 74LVX4245 is a 24–pin dual–supply, octal translating transceiver that is designed to interface between a 5.0 V bus and a 3.0 V bus in a mixed 3.0 V / 5.0 V supply environment such as laptop computers using a 3.3 V CPU and 5.0 V LCD display. The A port interfaces with the 5V bus; the B port interfaces with the 3.0 V bus.

The Transmit/Receive (T/\overline{R}) input determines the direction of data flow. Transmit (active–High) enables data from the A port to the B port. Receive (active–Low) enables data from the B port to the A port. The Output Enable (\overline{OE}) input, when High, disables both A and B ports by placing them in 3–State.

Features

- Bi-directional Interface Between 5.0 V and 3.0 V Buses
- Control Inputs Compatible with TTL Level
- 5.0 V Data Flow at A Port and 3.0 V Data Flow at B Port
- Outputs Source/Sink 24 mA at 5.0 V Bus and 12 mA at 3.0 V Bus
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- Available in SOIC and TSSOP Packages
- Functionally Compatible with the 74 Series 245
- Pb-Free Packages are Available*

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WL	= Wafer Lot
ΥY	= Year
WW	= Work Week

PIN NAMES

Pins	Function					
0E T/R A0-A7	Output Enable Input Transmit/Receive Input Side A 3–State Inputs or 3–State					
B0-B7	Outputs Side B 3–State Inputs or 3–State Outputs					

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.





INPUTS		
ŌE	T/R	Non–Inverting
L	L	B Data to A Bus
L	н	A Data to B Bus
Н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; For I_{CC} reasons, Do Not Float Inputs

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Condition	Unit
V _{CCA} , V _{CCB}	DC Supply Voltage		–0.5 to +7.0		V
VI	DC Input Voltage	OE , T/ R	–0.5 to V _{CCA} +0.5		V
V _{I/O}	DC Input/Output Voltage	An	–0.5 to V _{CCA} +0.5		V
		Bn	–0.5 to V _{CCB} +0.5		V
I _{IK}	DC Input Diode Current	$\overline{\text{OE}}, \text{T/R}$	±20	V _I < GND	mA
I _{ОК}	DC Output Diode Current		±50	$V_O < GND; V_O > V_{CC}$	mA
Ι _Ο	DC Output Source/Sink Current		±50		mA
I _{CC} , I _{GND}	DC Supply Current	Per Output Pin Maximum Current at I _{CCA} Maximum Current at I _{CCB}	±50 ±200 ±100		mA
T _{STG}	Storage Temperature Range		-65 to +150		°C
Latchup	DC Latchup Source/Sink Current		±300		mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Paramete	Min	Max	Unit	
V _{CCA} , V _{CCB}	Supply Voltage	V _{CCA} V _{CCB}	4.5 2.7	5.5 3.6	V
VI	Input Voltage	0	V _{CCA}	V	
V _{I/O}	Input/Output Voltage	An Bn	0 0	V _{CCA} V _{CCB}	V
T _A	Operating Free–Air Temperature			+85	°C
$\Delta t / \Delta V$	Minimum Input Edge Rate V_{IN} from 30% to 70% of $V_{CC};V_{CC}$ at 3.0V, 4.5V,	5.5V	0	8	ns/V

DC ELECTRICAL CHARACTERISTICS

						T _A = 25°C		T _A = −40 to +85°C	
Symbol	Parameter		Condition	V_{CCA}	V _{CCB}	Тур (Guaranteed Limits	
V _{IHA}	Minimum HIGH Level	An, OE T/R	V _{OUT} ≤ 0.1V	5.5 4.5	3.3 3.3		2.0 2.0	2.0 2.0	V
V _{IHB}	Input Voltage	Bn	$\geq V_{CC} - 0.1V$	5.0 5.0	3.6 2.7		2.0 2.0	2.0 2.0	V
V _{ILA}	Maximum LOW Level	An, OE T/R	V _{OUT} ≤ 0.1V	5.5 4.5	3.3 3.3		0.8 0.8	0.8 0.8	V
V _{ILB}	Input Voltage	Bn	$\geq V_{CC} - 0.1V$	5.0 5.0	2.7 3.6		0.8 0.8	0.8 0.8	V
V _{OHA}	Minimum HIGH Level		l _{OUT} = –100μA l _{OH} = –24mA	4.5 4.5	3.0 3.0	4.50 4.25	4.40 3.86	4.40 3.76	V
V _{OHB}	Output Voltage		I _{OUT} = -100μA I _{OH} = -12mA I _{OH} = -8mA	4.5 4.5 4.5	3.0 3.0 2.7	2.99 2.80 2.50	2.9 2.4 2.4	2.9 2.4 2.4	V
V _{OLA}	Maximum LOW Level		I _{OUT} = 100μA I _{OL} = 24mA	4.5 4.5	3.0 3.0	0.002 0.18	0.10 0.36	0.10 0.44	V
V _{OLB}	Output voltage		I _{OUT} = 100μA I _{OL} = 12mA I _{OL} = 8mA	4.5 4.5 4.5	3.0 3.0 2.7	0.002 0.1 0.1	0.10 0.31 0.31	0.10 0.40 0.40	V

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DC ELECTRICAL CHARACTERISTICS

						T _A = 25°C		T _A = −40 to +85°C	
Symbol	Parameter		Condition	V_{CCA}	V _{CCB}	Тур С		uaranteed Limits	Unit
I _{IN}	Max Input Leak- age Current	<u>OE,</u> T/R	$V_I = V_{CCA}, GND$	5.5	3.6		±0.1	±1.0	μΑ
I _{OZA}	Max 3–State Out- put Leakage	An		5.5	3.6		±0.5	±5.0	μΑ
I _{OZB}	Max 3–State Out- put Leakage	Bn	$ \begin{array}{c} V_{I} = V_{IH}, V_{IL} \\ \overline{OE} = V_{CCA} \\ V_{O} = V_{CCB}, GND \end{array} $	5.5	3.6		±0.5	±5.0	μΑ
ΔI_{CC}	Maximum I _{CCT} per Input	An, OE T/R	V _I =V _{CCA} -2.1V	5.5	3.6	1.0	1.35	1.5	mA
	Bn		V _I =V _{CCB} -0.6V	5.5	3.6		0.35	0.5	mA
I _{CCA}	Quiescent V _{CCA} Supply Current		An=V _{CCA} or GND Bn=V _{CCB} or GND OE=GND T/R=GND	5.5	3.6		8	80	μΑ
I _{CCB}	3 Quiescent V _{CCB} Supply Current		$\begin{array}{c} \text{An=V}_{\text{CCA}} \text{ or GND} \\ \text{Bn=V}_{\text{CCB}} \text{ or GND} \\ \overline{\text{OE}} = \text{GND} \\ \text{T/R} = \text{V}_{\text{CCA}} \end{array}$	5.5	3.6		5	50	μΑ
V _{OLPA} V _{OLPB}	Quiet Output Max Dynamic V _{OL}		Notes 1, 2	5.0 5.0	3.3 3.3		1.5 1.2		V
V _{OLVA} V _{OLVB}	A Quiet Output Min B Dynamic V _{OL}		Notes 1, 2	5.0 5.0	3.3 3.3		-1.2 -0.8		V
V _{IHDA} V _{IHDB}	Min HIGH Level Dynamic Input Voltage		Notes 1, 3	5.0 5.0	3.3 3.3		2.0 2.0	_	V
V _{ILDA} V _{ILDB}	Max LOW Level Dynamic Input Voltage		Notes 1, 3	5.0 5.0	3.3 3.3		0.8 0.8		V

Worst case package.
 Max number of outputs defined as (n). Data inputs are driven 0V to V_{CC} level; one output at GND.
 Max number of data inputs (n) switching. (n–1) inputs switching 0V to V_{CC} level. Input under test switching: V_{CC} level to threshold (V_{ILD}), 0V to threshold (V_{ILD}), f = 1MHz.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter		Condition		Unit
C _{IN}	Input Capacitance		$V_{CCA} = 5.0V; V_{CCB} = 3.3V$	4.5	pF
C _{I/O}	Input/Output Capacitance		$V_{CCA} = 5.0V; V_{CCB} = 3.3V$	15	pF
C _{PD}	Power Dissipation Capacitance B (Measured at 10MHz) A	8→A A→B	V _{CCA} = 5.0V V _{CCB} = 3.3V	55 40	pF

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AC ELECTRICAL CHARACTERISTICS

		T _A = −40 to +85°C C _L = 50pF			T _A = −40 to +85°C C _L = 50pF		
		V _C V _C	_{CA} = 5V ±0. _{CB} = 3.3V ±0	5V 9.3V	V _{CCA} = 5V ±0.5V V _{CCB} = 2.7V		
Symbol	Parameter	Min	Typ (Note 4)	Max	Min	Max	Unit
t _{PHL} t _{PLH}	Propagation Delay A to B	1.0 1.0	5.1 5.3	9.0 9.0	1.0 1.0	10.0 10.0	ns
t _{PHL} t _{PLH}	Propagation Delay B to A	1.0 1.0	5.4 5.5	9.0 9.0	1.0 1.0	10.0 10.0	ns
t _{PZL} t _{PZH}	Output Enable Time OE to B	1.0 1.0	6.5 6.7	10.5 10.5	1.0 1.0	11.5 11.5	ns
t _{PZL} t _{PZH}	Output Enable Time OE to A	1.0 1.0	5.2 5.8	9.5 9.5	1.0 1.0	10.0 10.0	ns
t _{PHZ} t _{PLZ}	Output Disable Time OE to B	1.0 1.0	6.0 3.3	10.0 7.0	1.0 1.0	10.0 7.5	ns
t _{PHZ} t _{PLZ}	Output Disable Time OE to A	1.0 1.0	3.9 2.9	7.5 7.0	1.0 1.0	7.5 7.5	ns
t _{OSHL} t _{OSLH}	Output to Output Skew, Data to Output (Note 5)		1.0	1.5		1.5	ns

 Typical values at V_{CCA} = 5.0V; V_{CCB} = 3.3V at 25°C.
 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LVX4245DW	SOIC-24	30 Units / Rail
MC74LVX4245DWR2	SOIC-24	1000 Tape & Reel
MC74LVX4245DWR2G	SOIC-24 (Pb-Free)	1000 Tape & Reel
MC74LVX4245DT	TSSOP-24*	62 Units / Rail
MC74LVX4245DTR2	TSSOP-24*	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*This package is inherently Pb–Free.

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Dual Supply Octal Translating Transceiver

The 74LVX4245 is a is a dual–supply device well capable of bidirectional signal voltage translation. This level shifting ability provides an excellent interface between low voltage CPU local bus and a standard 5.0 V I/O bus. The device control inputs can be controlled by either the low voltage CPU and core logic or a bus arbitrator with 5.0 V I/O levels.

The LVX4245 is ideal for mixed voltage applications such as notebook computers using a 3.3 V CPU and 5.0 V peripheral devices.

Applications:

Mixed Mode Dual Supply Interface Solutions

The LVX4245 is designed to solve 3.0 V / 5.0 V interfaces when CMOS devices cannot tolerate I/O levels above their applied V_{CC}. If an I/O pin of a 3.0 V device is driven by a 5.0 V device, the P–Channel transistor in the 3.0 V device will conduct – causing current flow from the I/O bus to the 3.0 V power supply. The result may be destruction of the 3.0 V device through latchup effects. A current limiting resistor may be used to prevent destruction, but it causes speed degradation and needless power dissipation.

A better solution is provided in the LVX4245. It provides two different output levels that easily handle the dual voltage interface. The A port is a dedicated 5.0 V port; the B port is a dedicated 3.0 V port.

Since the LVX4245 is a '245 transceiver, the user may either use it for bidirectional or unidirectional applications. The center 20 pins are configured to match a '245 pinout. This enables the user to easily replace this level shifter with a 3.0 V '245 device without additional layout work or remanufacture of the circuit board (when both buses are 3.0 V).



Figure 3. 3.3V/5V Interface Block Diagram

Powering Up the LVX4245

When powering up the LVX4245, please note that if the V_{CCB} pin is powered–up well in advance of the V_{CCA} pin, several milliamps of either I_{CCA} or I_{CCB} current will result. If the V_{CCA} pin is powered–up in advance of the V_{CCB} pin then only nanoamps of Icc current will result. In actuality the V_{CCB} can be powered "slightly" before the V_{CCA} without the current penalty, but this "setup time" is dependent on the power–up ramp rate of the V_{CC} pins. With a ramp rate of approximately 50 mV/ns (50V/µs) a 25 ns setup time was observed (V_{CCB} before V_{CCA}). With a 7.0 V/µs rate, the setup time was about 140ns. When all is said and done, the safest powerup strategy is to simply power V_{CCA} before V_{CCB}. One more note: if the V_{CCB} ramp rate is faster than the V_{CCA} ramp rate then power problems might still occur, even if the V_{CCA} powerup began prior to the V_{CCB} powerup.

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Figure 4. MC74LVX4245 Fits Into a System with 3V Subsystem and 5V Subsystem





Figure 5. MC74LVX4245 Pin Arrangement Is Compatible to 20–Pin 74 Series '245s

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WAVEFORM 1 - PROPAGATION DELAYS

 t_R = t_F = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns



 $\begin{array}{l} \textbf{WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES} \\ \hline t_R = t_F = 2.5 \text{ns}, 10\% \text{ to } 90\%; f = 1 \text{MHz}; t_W = 500 \text{ns} \end{array}$





TEST	SWITCH
t _{PLH} , t _{PHL} , t _{PZH} , t _{PHZ}	Open
t _{PZL} , t _{PLZ}	$2 \times V_{CC}$

 C_L = 50pF or equivalent (Includes jig and probe capacitance)

 $R_{L}^{-} = R_{1} = 500\Omega$ or equivalent

 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)



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PACKAGE DIMENSIONS

SOIC-24 **DW SUFFIX** CASE 751E-04 **ISSUE E**



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	15.25	15.54	0.601	0.612
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27	BSC	0.050 BSC	
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0 °	8°	0 °	8 °
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

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PACKAGE DIMENSIONS

TSSOP-24 DT SUFFIX CASE 948H-01 ISSUE A



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INCHES

MIN MAX

0.002 0.006

0.020 0.030

0.026 BSC

0.252 BSC

0.047

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0.303 0.311

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0.011

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MC74LVX4245/D